

Description

The DFI300HF12I4ME1 is a Half Bridge IGBT Power Module. It integrates high performance IGBT chips designed for the applications such as High Power supply and Motor control.



Features

- Blocking voltage:1200V
- Low saturation voltage $V_{CE(sat)}$
- Low Switching Losses
- Thermistor inside

Applications

- High Power Switching Applications
- Motor Drives
- Solar inverter Systems
- Wind Turbines

Circuit diagram

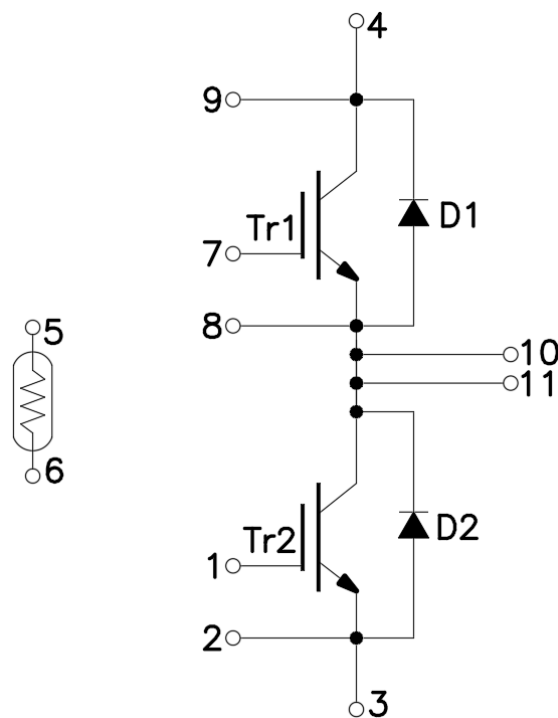


Figure 1. Out drawing & circuit diagram for DFI300HF12I4ME1

Pin Configuration and Marking Information

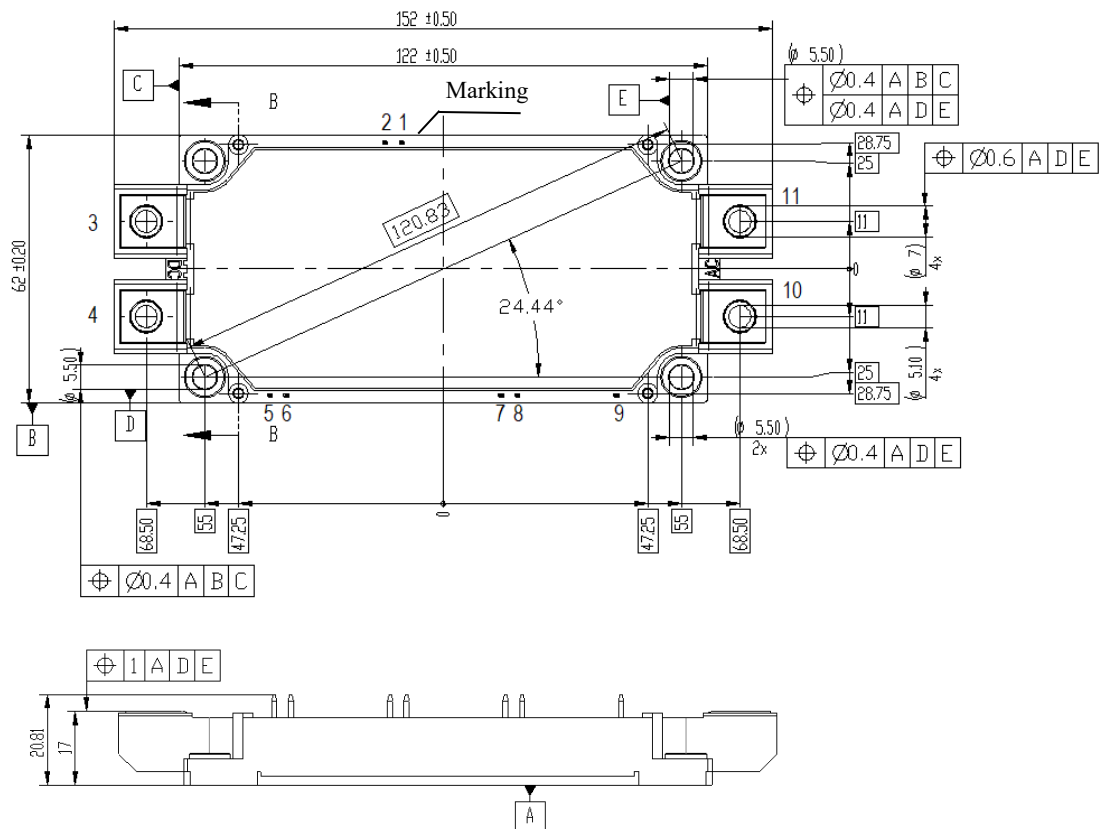


Figure 2. Pin configuration

Module

Parameter	Conditions	Value	Unit
Isolation Voltage	RMS, f=50Hz, t=1min	3.4	KV
Material of module baseplate	-	Cu	-
Creepage distance	terminal to heatsink terminal to terminal	14.5 13	mm
Clearance	terminal to heatsink terminal to terminal	13 10.5	mm
CTI	-	>200	-
Module lead resistance, terminals – chip	T _c =25°C	0.99	mΩ
Mounting torque for module mounting	M5, M6	3 to 6	Nm
Weight	-	350	g

Maximum Ratings (T_j=25°C unless otherwise specified)

Symbol	Parameter	Conditions	Ratings	Unit
V _{CES}	Collector-Emitter Voltage	G-E Short	1200	V
V _{GES}	Gate-Emitter Voltage	C-E Short	±20	V
I _C	DC Continuous Collector Current	T _C =100°C	300	A
I _{CM}	Pulse Collector Current	t _p =1ms, Note1	600	A
P _C	Maximum Power Dissipation	T _C =25°C, T _j =175°C(IGBT)	1364	W
I _F	Diode forward Current	-	300	A
I _{FRM}	Repetitive peak forward Current	t _p =1ms, Note1	600	A
T _j	junction temperature	-	-40 to 175	°C
T _{stg}	Storage temperature	-	-40 to 125	°C

Note1: Pulse width limited by maximum junction temperature

NTC characteristics

Symbol	Parameter	Condition	Value			Unit
			Min.	Typ.	Max.	
R ₂₅	Resistance	T _C =25°C	-	5	-	kΩ
ΔR/R	Deviation of R100	T _C =100°C, R ₁₀₀ =493Ω	5	-	5	%
P ₂₅	Power dissipation	T _C =25°C	-	-	20	mW
B _{25/50}	B-value	$R_2 = R_{25} \exp [B_{25/50}(1/T_2 - 1/(298,15 \text{ K}))]$	-	3375	-	K
B _{25/80}	B-value	$R_2 = R_{25} \exp [B_{25/80}(1/T_2 - 1/(298,15 \text{ K}))]$	-	3411	-	K
B _{25/100}	B-value	$R_2 = R_{25} \exp [B_{25/100}(1/T_2 - 1/(298,15 \text{ K}))]$	-	3433	-	K

IGBT Electrical characteristics (T_j=25°C unless otherwise specified, chip)

Symbol	Item	Condition		Value			Unit
				Min.	Typ.	Max	
V _{CE(sat)} (Chip)	Collector-Emitter Saturation Voltage	I _C =300A V _{GE} =15V	T _J =25°C	-	1.65	1.95	V
			T _J =125°C	-	1.85	-	V
			T _J =150°C	-	1.90	-	V
V _{GE(th)}	Gate-Emitter threshold Voltage	I _C =11.4mA, V _{CE} =V _{GE}		5.0	5.6	6.8	V
R _{Gint}	Internal gate resistor	-	T _J =25°C	-	2.5	-	Ω
C _{ies}	Input Capacitance	V _{CE} =25V, V _{GE} =0V f =1MHz	T _J =25°C	-	24.9	-	nF
C _{res}	Reverse transfer Capacitance			-	0.87	-	nF
I _{CES}	Collector- Emitter Cut off Current	V _{CE} =1200V, V _{GE} =0V	T _J =25°C	-	-	1	mA
I _{GES}	Gate-Emitter Leakage Current	V _{GE} =20V, V _{CE} =0V	T _J =25°C	-	-	600	nA
t _{d(on)}	Turn-on delay time	V _{CC} =600V I _C =300A V _{GE} =+15V/-15V R _G =0.5Ω Inductive load	T _J =25°C	-	125	-	ns
			T _J =125°C	-	136	-	
			T _J =150°C	-	149	-	
t _r	Rise time		T _J =25°C	-	30	-	ns
			T _J =125°C	-	35	-	
			T _J =150°C	-	40	-	
t _{d(off)}	Turn-off delay time		T _J =25°C	-	300	-	ns
			T _J =125°C	-	321	-	
			T _J =150°C	-	342	-	
t _f	Fall time		T _J =25°C	-	165	-	ns
			T _J =125°C	-	178	-	
			T _J =150°C	-	189	-	
E _{on}	Turn-on power dissipation		T _J =25°C	-	7.2	-	mJ
			T _J =125°C	-	9.6	-	
			T _J =150°C	-	12.3	-	
E _{off}	Turn-off power dissipation		T _J =25°C	-	22.5	-	mJ
			T _J =125°C	-	24.6	-	
			T _J =150°C	-	29.1	-	
I _{SC}	V _{GE} ≤15V, V _{CC} =800V, t _p ≤10us, T _{VJ} =150°C			-	1102	-	A
R _{th(j-c)}	Thermal Resistance, Junction to Case (IGBT)			-	0.11	-	°C/W

Freewheeling Diode Electrical characteristics (T_j=25°C unless otherwise specified, chip)

Symbol	Item	Condition		Value			Unit
				Min.	Typ.	Max	
V _F	Diode Forward Voltage	I _F =300A, V _{GE} =0V	T _j =25°C	-	2.0	2.4	V
			T _j =125°C	-	1.7	-	
			T _j =150°C	-	1.6	-	
I _{RM}	Peak reverse recovery Current	(Switch side) V _{CC} =600V, I _C =300A V _{GE} =± 15V	T _j =25°C	-	182	-	us
			T _j =125°C	-	192	-	
			T _j =150°C	-	202	-	
Q _{rr}	Recovered charge	R _G =0.5Ω (FRD side) V _{RR} =600V, I _F =300A	T _j =25°C	-	40	-	A
			T _j =125°C	-	45.1	-	
			T _j =150°C	-	48.2	-	
E _{rr}	Reverse recovered energy	V _{GE} =-15V Inductive load switching operation	T _j =25°C	-	12.1	-	uC
			T _j =125°C	-	13.2	-	
			T _j =150°C	-	16.5	-	
R _{th(j-c)}	Thermal Resistance, Junction to Case (Diode)			-	0.15	-	°C/W

Test Conditions

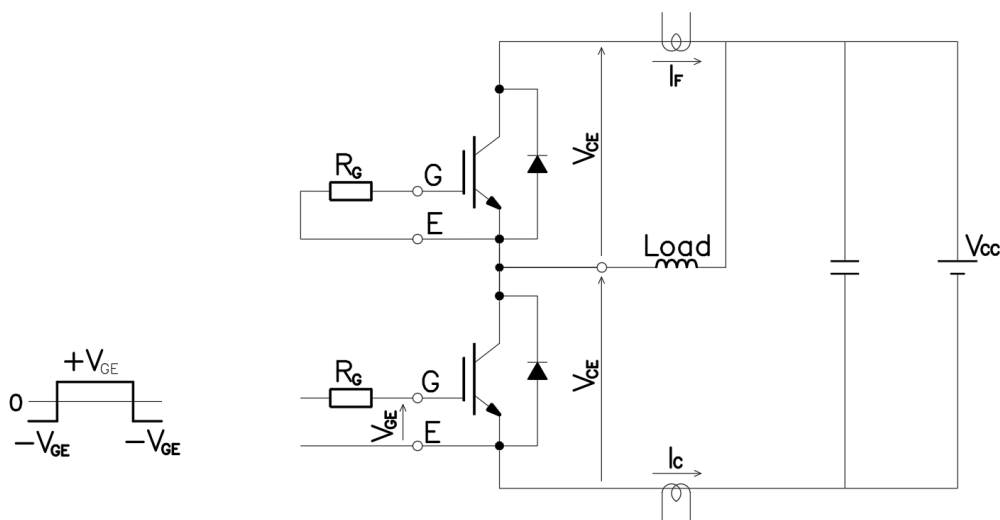


Figure 3. Switching time measure circuit

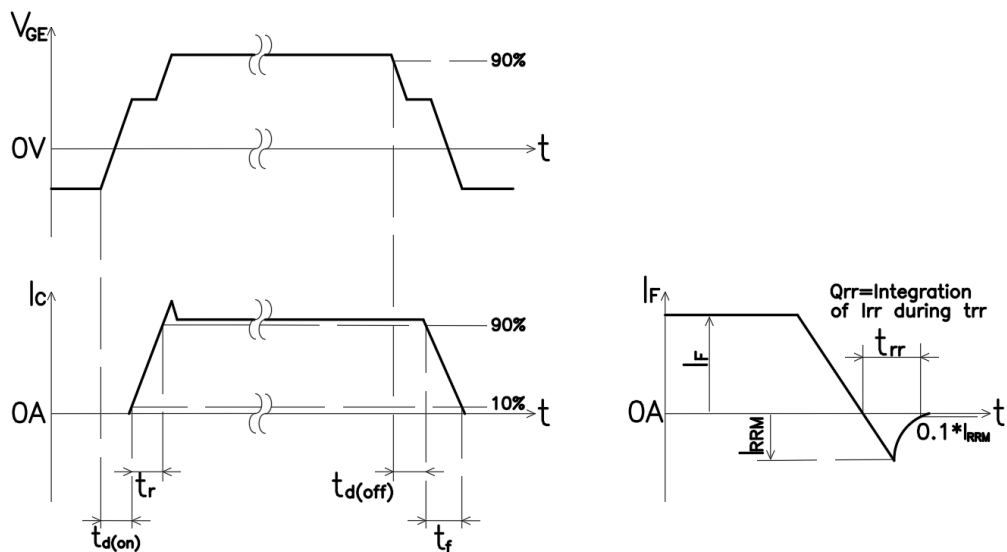


Figure 4. Switching time definition

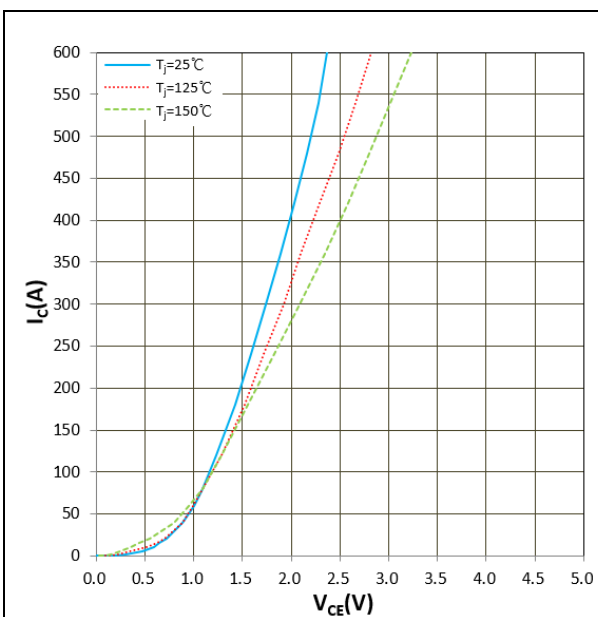


Figure 5. I_c vs V_{GE}
 $V_{GE} = 15V$

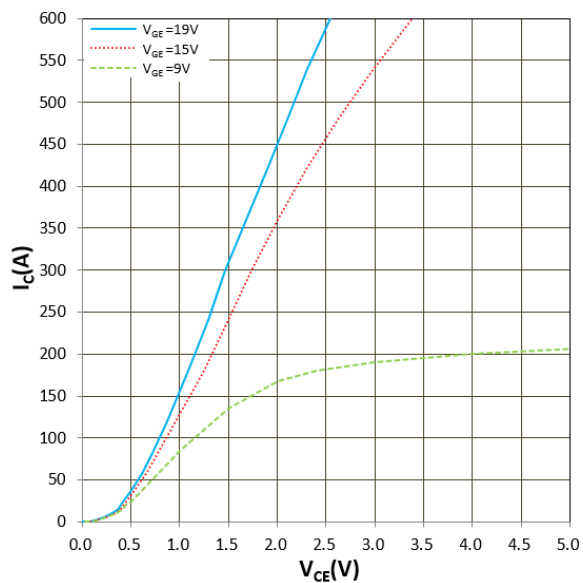


Figure 6. I_c vs V_{GE}
 $T_j = 25^\circ C$

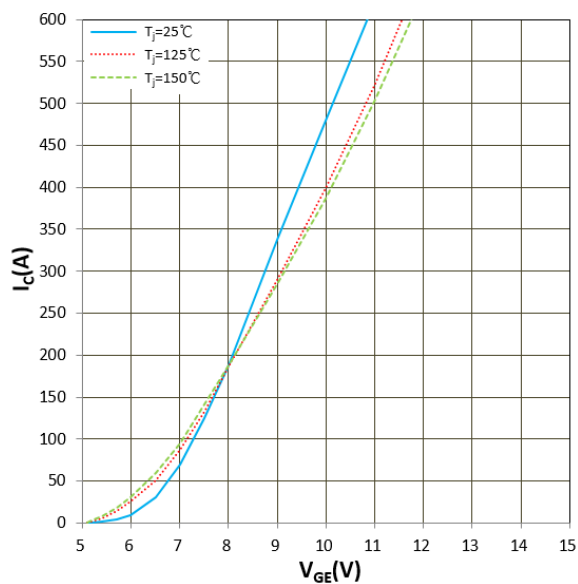


Figure 7. I_c vs V_{GE}
 $V_{CE} = 20\text{V}$

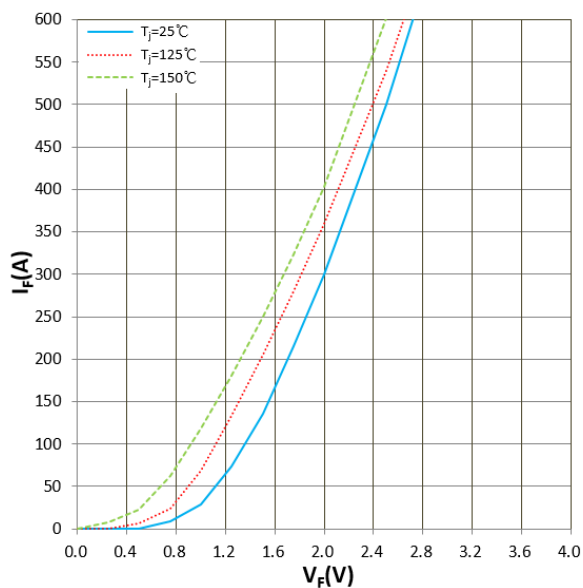


Figure 8. I_F vs V_F

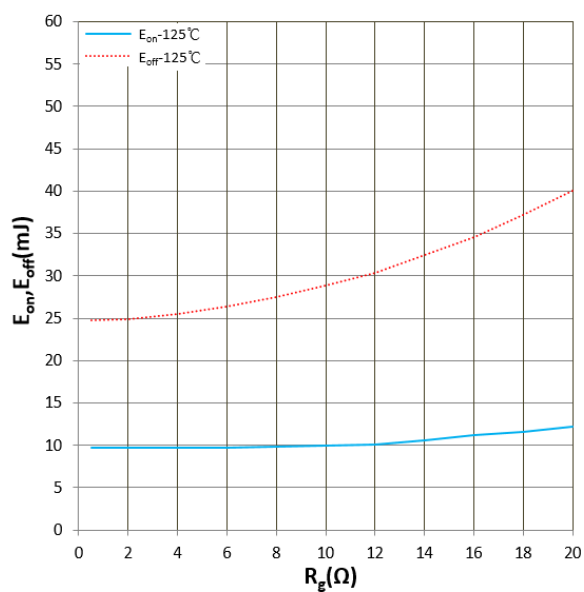


Figure 9. E_{on} , E_{off} vs R_g
 $V_{CC} = 600\text{V}$, $V_{GE} = \pm 15\text{V}$, $I_c = 300\text{A}$

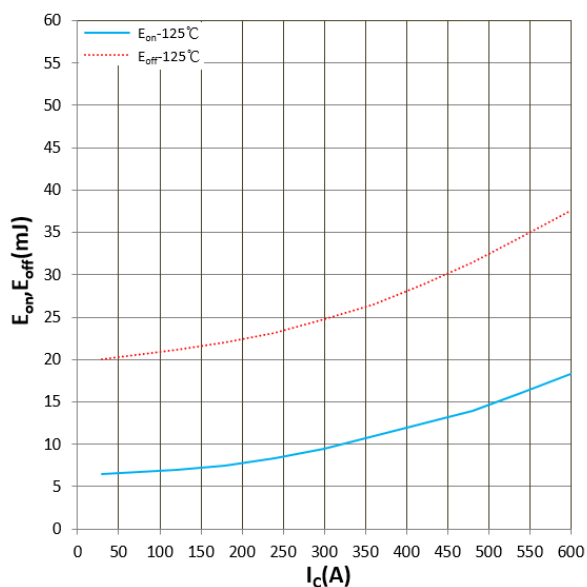


Figure 10. E_{on} , E_{off} vs I_c
 $V_{CC} = 600\text{V}$, $V_{GE} = \pm 15\text{V}$, $R_g = 0.5\Omega$

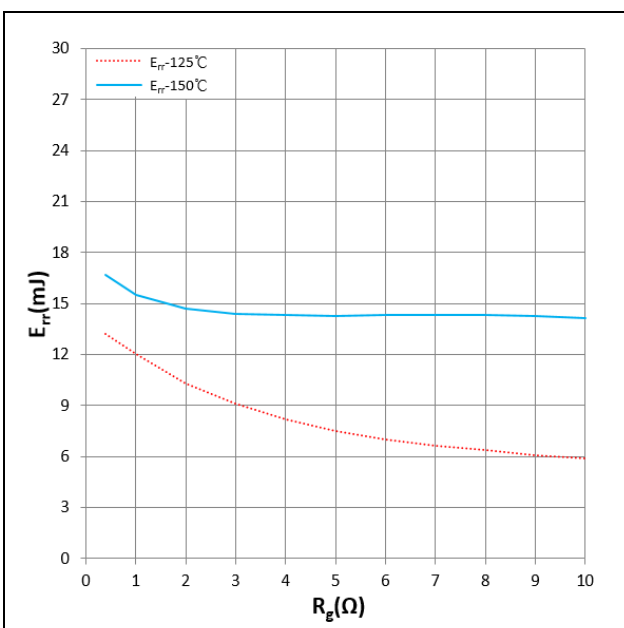


Figure 11. E_{rr} vs R_g
 $V_{CC}=600V$, $I_C=300A$

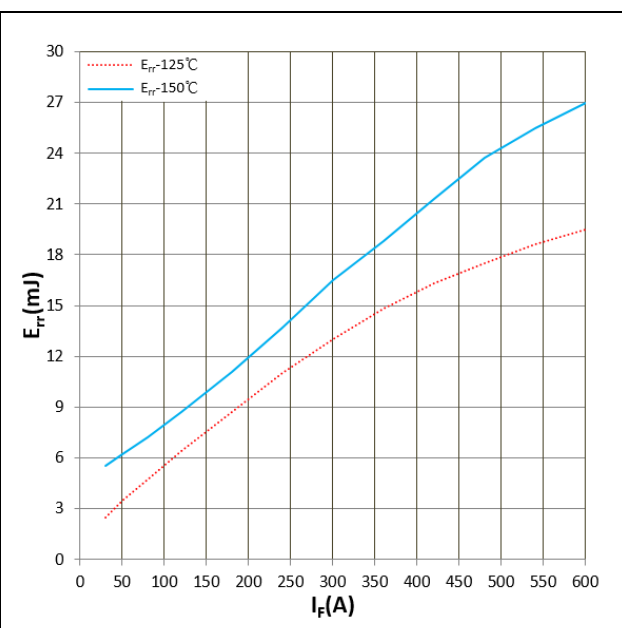


Figure 12. E_{rr} vs I_F
 $V_{CC}=600V$, $R_G=0.5\Omega$

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Changes to this product data sheet are reserved.

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